

FFPF04S60S

Features

- High Speed Switching, $t_{rr} < 25$ ns @ $I_F = 4$ A
- High Reverse Voltage and High Reliability
- · RoHS compliant

Applications

- · General Purpose
- Switching Mode Power Supply
- Boost Diode in continuous mode power factor corrections
- · Power switching circuits



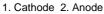
October 2007 STEALTHTM II Rectifier

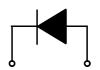
4A, 600V STEALTH™ II Rectifier

The FFPF04S60S is STEALTHTM II rectifier with soft recovery characteristics. It is silicon nitride passivated ion-implanted epitaxial planar construction.

This device is intended for use as freewheeling of boost diode in switching power supplies and other power switching applications. Their low stored charge and hyperfast soft recovery minimize ringing and electrical noise in many power switching circuits reducing power loss in the switching transistors.







1. Cathode 2. Anode

Absolute Maximum Ratings T_C = 25°C unless otherwise noted

Symbol	Parameter	Ratings	Units
V_{RRM}	Peak Repetitive Reverse Voltage	600	V
V_{RWM}	Working Peak Reverse Voltage	600	V
V_R	DC Blocking Voltage	600	V
I _{F(AV)}	Average Rectified Forward Current @ T _C = 116°C	4	Α
I _{FSM}	Non-repetitive Peak Surge Current 60Hz Single Half-Sine Wave	40	А
T _J , T _{STG}	Operating and Storage Temperature Range	-65 to +150	°C

Thermal Characteristics

Symbol	Parameter	Ratings	Units
$R_{\theta JC}$	Maximum Thermal Resistance, Junction to Case	6.8	°C/W

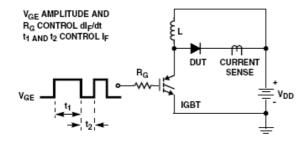
Package Marking and Ordering Information

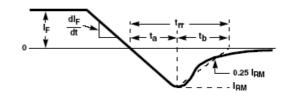
Device Marking	Device	Package	Reel Size	Tape Width	Quantity
F04S60S	FFPF04S60STU	TO-220F-2L	-	-	50

Electrical Characteristics $T_C = 25^{\circ}C$ unless otherwise noted

Symbol	Parameter		Min.	Тур.	Max.	Units
V _{FM} 1	$I_F = 4A$ $I_F = 4A$	$T_{\rm C} = 25^{\rm o}{\rm C}$ $T_{\rm C} = 125^{\rm o}{\rm C}$		2.2 1.7	2.6	V
I _{RM} 1	V _R = 600V V _R = 600V	$T_{\rm C} = 25^{\rm o}{\rm C}$ $T_{\rm C} = 125^{\rm o}{\rm C}$			100 500	μА
t _{rr}	$I_F = 1A$, di/dt = 100A/ μ s, $V_R = 30V$	$T_{\rm C} = 25^{\rm o}{\rm C}$	-	16	23	ns
t _{rr} I _{rr} S factor Q _{rr}	$I_F = 4A$, di/dt = 200A/ μ s, $V_R = 390V$	T _C = 25°C		18 2 0.7 18	25 - - -	ns A nC
t _{rr} I _{rr} S factor Q _{rr}	$I_F = 4A$, di/dt = 200A/ μ s, $V_R = 390V$	T _C = 125°C		45 2.8 1.8 64		ns A nC
W _{AVL}	Avalanche Energy (L = 40mH)	ı	10	=	-	mJ

Test Circuit and Waveforms



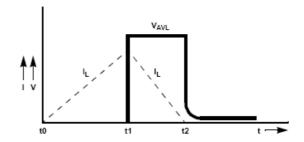


L = 40mH R < 0.1Ω

 $V_{DD} = 50V$

 $\mathsf{EAVL} = 1/2\mathsf{LI2} \; [\mathsf{V}_{\mathsf{R}(\mathsf{AVL})}/(\mathsf{V}_{\mathsf{R}(\mathsf{AVL})} - \mathsf{V}_{\mathsf{DD}})]$

Q1 = IGBT ($BV_{CES} > DUT V_{R(AVL)}$) CURRENT V_{DD} SENSE



 v_{DD}

Notes: 1: Pulse: Test Pulse width = 300μ s, Duty Cycle = 2%

Typical Performance Characteristics

Figure 1. Typical Forward Voltage Drop vs. Forward Current

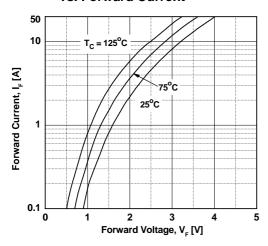


Figure 3. Typical Junction Capacitance

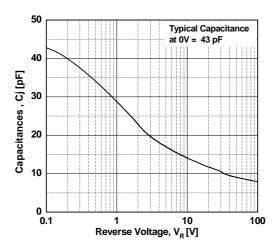


Figure 5. Typical Reverse Recovery Current vs. di/dt

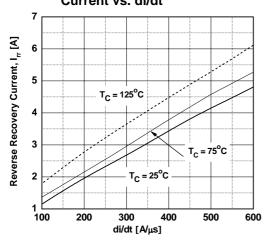


Figure 2. Typical Reverse Current vs. Reverse Voltage

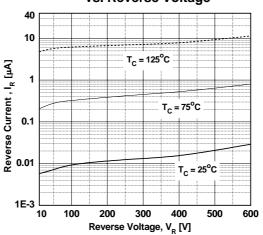


Figure 4. Typical Reverse Recovery Time vs. di/dt

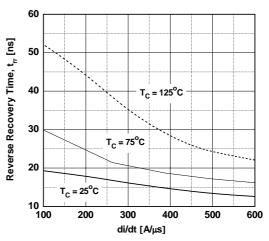
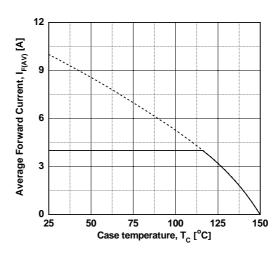
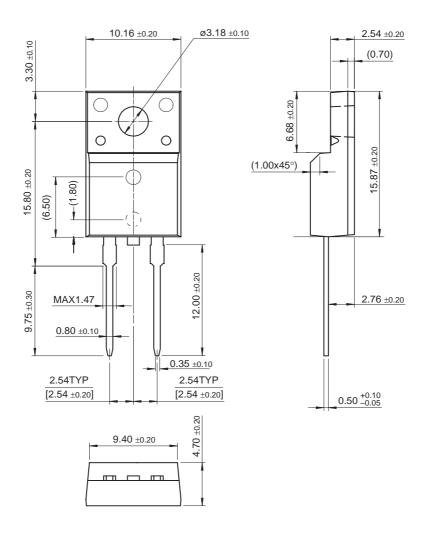


Figure 6. Forward Current Derating Curve



Mechanical Dimensions

TO-220F 2L



Dimensions in Millimeters



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